A fluorine plasma resistant coating on a ceramic substrate is disclosed. In one embodiment the composition includes an AION coating that is about 2 microns thick that overlies a substrate, and having an optional yttria coating layer that is about 3 microns thick overlies the AION coating.
AION COATED SUBSTRATE WITH OPTIONAL YTTRIA OVERLAYER

RELATED APPLICATION

This application claims the benefit of U.S. Provisional Application No. 61/521,822, filed on August 10, 2011. The entire teachings of the above application are incorporated herein by reference.

BACKGROUND OF THE INVENTION

There is a continuing need for coatings on quartz and other ceramic substrates that are resistant to fluorine plasma. These substrates are transparent and often used in coating and etching systems used in semiconductor manufacturing. Fluorine plasma can damage these substrates creating particulates that can contaminate semiconductor process wafers. In semiconductor manufacturing aluminum can also be a source of contamination of semiconductor wafers.

SUMMARY OF THE INVENTION

The invention pertains to aluminum oxynitride (AION) coated substrates, such as quartz, aluminum alloys, steels, alumina, metals, alloys and other substrates that come into contact with fluorine plasma. The AION coating is deposited onto the substrate by reactive pulsed DC magnetron sputtering processes to a thickness of from about 1 micron to about 10 microns.

AION can be the only coating on the substrate or it can have an overlay of yttria to form a dual layer coating on the substrate. The thickness of the layers will depend upon the proximity of the substrate to the fluorine plasma source and the intensity of the plasma. The yttria layer can be deposited on the AION layer by the same method of deposition as used for the AION layer to a thickness of from about 1 micron to about 10 microns.

In one embodiment, when AION is the only coating on the substrate, the coating thickness is from about 5 to about 6 microns.
In another embodiment, when yttria is overlaid on the AION coating, the combined coating thickness of the yttria and AION layers can be from about 5 to about 6 microns.

The coatings are highly pure and their morphologies, as seen by Scanning Electron Microscopy (SEM), are smooth, dense and exhibit homogeneous microstructures, without columnar structures that would weaken the coating under the fluorine plasma conditions. The coatings are able to conform to the substrate’s surface. The AION coating with optional yttria overlay provides improved resistance to fluorine plasma corrosion and reduces particle contamination.

BRIEF DESCRIPTION OF THE DRAWINGS

The drawings accompanying and forming part of this specification are included to depict certain aspects of the invention. A clearer impression of the invention, and of the components and operation of systems provided with the invention, will become more readily apparent by referring to the exemplary, and therefore nonlimiting, embodiments illustrated in the drawings, wherein identical reference numerals designate the same components. Note that the features illustrated in the drawings are not necessarily drawn to scale.

FIG. 1A is a micrograph of the AION surface showing its morphology.

FIG. 1B shows the elemental composition of both AION coatings and AION ceramic as analyzed by X-ray photoelectron spectroscopy (XPS).

FIG. 1C shows SEM images from AION cross section and morphology.

FIG. 1D shows SEM images from yttria cross section and morphology.

FIG. 1E shows a micrograph of the yttria coating morphology.

FIG. 1F shows an analysis for the frontside of a coating flake showing aluminum, yttria, oxygen and fluorine.

FIG. 2 shows the analysis for the backside of a coating flake.

FIG. 3 shows an SEM micrograph of a sample exposed to fluorine plasma environment.

FIG. 4 shows a sample of quartz with yttria (yttrium 25%, oxygen 75%) coating and AION (41% Al, 57% oxygen, 2% nitrogen) barrier layer exposed to a
fluorine plasma; AION coating overlies the quartz. The labeled layers have a composition by EDS that substantially corresponds to the composition of the layer; layers 1 and 2 are similar to yttria, layer 3 AION, layer 4 quartz. Note that there is no detectable Aluminum in layer 1 and no detectable fluorine in layer 4.

FIG. 5 shows intact yttria coating.

FIG. 6 illustrates a yttria only coating on a quartz substrate.

FIG. 7 shows micrographs of the backside of yttria coating (peeled).

FIG. 8 shows micrographs of the backside of yttria coating (peeled).

FIG. 9 shows micrographs of the frontside of yttria coating (peeled).

FIG. 10 shows scanning electron micrographs (SEM) of yttria coating that was exposed to a fluorine plasma. Two regions of the yttria coating, a grain and a columnar region are shown in the bottom SEM. The Energy-dispersive X-ray spectroscopy (EDS) spectra for each of these regions are also shown. The inventors observed the problem that the "columnar" region appears to show more fluorine (11%) compared to the amount of fluorine in the "grain" region (0%) of the coating, and without wishing to be bound by theory it appears that the columnar region allows fluorine from the fluorine plasma to penetrate the yttria coating in these areas which can subsequently damage the underlying quartz.

FIG. 11 shows scanning electron micrographs of yttria coating (flakes).

FIG. 12 shows scanning electron micrographs taken of the different parts of the quartz substrate, as shown in the center illustration.

FIG. 13 shows the attack of fluorine plasma on the quartz through the columnar grain structure of the yttria coating.

FIG. 14 shows the attack of fluorine plasma on the quartz through the columnar grain structure of the yttria coating.

FIG. 15 shows scanning electron micrographs of the frontside and backside of a quartz substrate without yttria coating.

FIG. 16 shows an EDS scan of the frontside and backside of a quartz substrate without yttria coating.

FIG. 17 shows scanning electron micrographs from the frontside and backside of yttria coated quartz.
FIG. 18 shows the EDS scans from the frontside and backside of a yttria coated quartz substrate.

FIG. 19 shows an electron scanning micrograph of the edge of a yttria coated quartz sample.

FIG. 20 shows FT-IR transmittance spectra (wavelength 2.5 to 8 \( \mu \text{m} \)) of AION coating, AION ceramic and sapphire samples.

DETAILED DESCRIPTION OF THE INVENTION

A description of example embodiments of the invention follows.

While various compositions and methods are described, it is to be understood that this invention is not limited to the particular molecules, compositions, designs, methodologies or protocols described, as these may vary. It is also to be understood that the terminology used in the description is for the purpose of describing the particular versions or embodiments only, and is not intended to limit the scope of the present invention which will be limited only by the appended claims.

It must also be noted that as used herein and in the appended claims, the singular forms "a", "an", and "the" include plural reference unless the context clearly dictates otherwise. Thus, for example, reference to an "AION" coating is a reference to one or more layers of AION and equivalents thereof known to those skilled in the art, and so forth. Reference to a "yttria" coating is a reference to one or more layers of yttria and equivalents thereof known to those skilled in the art, and so forth.

Unless defined otherwise, all technical and scientific terms used herein have the same meanings as commonly understood by one of ordinary skill in the art. Methods and materials similar or equivalent to those described herein can be used in the practice or testing of embodiments of the present invention. All publications mentioned herein are incorporated by reference in their entirety. Nothing herein is to be construed as an admission that the invention is not entitled to antedate such disclosure by virtue of prior invention. "Optional" or "optionally" means that the subsequently described event or circumstance may or may not occur, and that the description includes instances where the event occurs and instances where it does not. All numeric values herein can be modified by the term "about," whether or not
explicitly indicated. The term "about" generally refers to a range of numbers that one of skill in the art would consider equivalent to the recited value (i.e., having the same function or result). In some embodiments the term "about" refers to ±10% of the stated value, in other embodiments the term "about" refers to ±2% of the stated value. While compositions and methods are described in terms of "comprising" various components or steps (interpreted as meaning "including, but not limited to"), the compositions and methods can also "consist essentially of" or "consist of" the various components and steps, such terminology should be interpreted as defining essentially closed or closed member groups.

Although the invention has been shown and described with respect to one or more implementations, equivalent alterations and modifications will occur to others skilled in the art based upon a reading and understanding of this specification and the annexed drawings. The invention includes all such modifications and alterations and is limited only by the scope of the following claims. In addition, while a particular feature or aspect of the invention may have been disclosed with respect to only one of several implementations, such feature or aspect may be combined with one or more other features or aspects of the other implementations as may be desired and advantageous for any given or particular application. Furthermore, to the extent that the terms "includes", "having", "has", "with", or variants thereof are used in either the detailed description or the claims, such terms are intended to be inclusive in a manner similar to the term "comprising." Also, the term "exemplary" is merely meant to mean an example, rather than the best. It is also to be appreciated that features, layers and/or elements depicted herein are illustrated with particular dimensions and/or orientations relative to one another for purposes of simplicity and ease of understanding, and that the actual dimensions and/or orientations may differ substantially from that illustrated herein.

The problem of protecting quartz and other ceramic substrates from fluorine plasma while minimizing aluminum contamination is solved by depositing an aluminum oxynitride (AION) coating of about 1 micron to 10 microns on a ceramic like quartz, and then overcoating the AION with a yttria coating of about 1 micron to 10 microns. The combination of these coatings provides a composite that is
transparent and that can withstand fluorine plasma processing as evidenced by no fluorine present by EDS (Energy-dispersive X-ray spectroscopy) analysis of a coated quartz substrate. The coating adheres to the underlying quartz or ceramic substrate as determined by the Scotch® Tape (available from 3M) test. The overlying yttria coating does not contain aluminum. The combination of AION and yttria coating the quartz substrate provides improved resistance to fluorine plasma corrosion than a yttria only coating on quartz and reduces the particle contamination.

Without wishing to be bound by theory, the inventor has discovered that for a yttria only coating on quartz, the fluorine from a fluorine plasma appears to penetrate through the columnar structure of the yttria and attack the underlying quartz. A solution to this problem is a layer of AION on top of the quartz, and then an optional layer of yttria over the AION.

One version of the invention is a composition that includes an AION coating that is about 2 microns thick that overlies a quartz substrate, a yttria coating layer that is about 3 microns thick overlies the AION coating. The AION and yttria coatings can be deposited by pulsed reactive physical vapor deposition. Deposition of AION results in a coating is close to the stoichiometric composition of the bulk AION. Aluminum oxynitride ceramic is available under the trademark ALON® Optical Ceramic by Surmet Corporation.

The AION composition and properties are provided in Table 1.

<table>
<thead>
<tr>
<th>Composition (at.%, +/-1%)</th>
<th>Purity (at.%)</th>
<th>Hardness (DPHN)</th>
<th>Elastic Modulus (Gpa)</th>
<th>Electrical Resistivity (Ω·cm)</th>
<th>Roughness (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Al O N</td>
<td>99.95%</td>
<td>1300</td>
<td>190</td>
<td>&gt;10^12</td>
<td>2</td>
</tr>
<tr>
<td>41% 57% 2.0%</td>
<td></td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
Yttria composition and properties are provided in Table 2.

Table 2

<table>
<thead>
<tr>
<th>Composition (at.%, +/-1%)</th>
<th>Purity (at.%)</th>
<th>Hardness (DPHN)</th>
<th>Elastic Modulus (Gpa)</th>
<th>Electrical Resistivity (Ω/□)</th>
<th>Roughness (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Y</td>
<td>O</td>
<td>99.95%</td>
<td>1400</td>
<td>&gt;10^{12}</td>
<td>8</td>
</tr>
<tr>
<td>25%</td>
<td>75%</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
</tbody>
</table>

Although the examples provided below use quartz as the substrate, any substrate that comes into contact with fluorine plasma can be used in the invention. Furthermore, any substrate containing aluminum in which it is desirable to prevent its contact with fluorine can be used as the substrate in the invention. Examples of suitable substrates include but are not limited to aluminum containing ceramics, steels, aluminum, alumina, quartz and other metals, alloys and ceramics. It will be apparent to the skilled person that the substrate to be coated will be any equipment used in semiconductor manufacturing that comes into contact with the fluorine plasma environment, such as but not limited to chamber and chamber components, wafer susceptor or chuck, showerhead, liners, rings, nozzles, baffles and fasteners, and wafer transport components.

EXAMPLES

EXAMPLE 1

Example 1 illustrates an embodiment of the invention where an AION coating (barrier layer, available from Entegris, Inc., Billerica, MA) made by pulsed reactive physical vapor deposition technique is coated on a quartz substrate. The AION was overcoated with a layer of yttria (available from Entegris Inc.) The coated sample was exposed to a fluorine plasma environment. Chemical analysis showed that the top layer contained no aluminum, but had a composition similar to yttria. This result shows that a fluorine resistant coating overlying quartz can be made with AION, but can be capped with a protective coating of yttria that does not include aluminum.
Details of the yttria coated quartz sample are as follows:

- Total thickness of 5 um yttria with barrier layer was deposited on quartz substrate.
- Delaminating observed around outer edge of quartz, but most coating still adhered on substrate without peeling off by Scotch® tape test.
- Three types of sample were analyzed by SEM and EDS
  - Both sides of coating flakes peeling off from quartz substrate
  - Exposed quartz substrate previously coated
  - Intact coated quartz surface
- Due to non-electrical conduction of yttria coating and quartz, charging may affect quality of SEM images.

**Summary of Observations**

- Yttria coating with barrier layer exhibited improved resistance to fluorine corrosion than previous yttria only coating.
- Different morphology and composition observed on adhered yttria coating and peeled yttria flakes from edge of quartz substrate.
  - Plasma intensity at the edge

See FIGS. IF to FIG. 5. Elemental composition of both AION coatings and AION ceramic were analyzed by X-ray photoelectron spectroscopy (XPS) and the results are shown in FIG. IB.

**EXAMPLE 2**

Example 2 is a comparative example of yttria only coating on a quartz substrate.

- 5 um yttria was deposited on quartz substrate.
- Delaminating of yttria coating observed after being processed in oxygen and fluorine plasma environment.
- Three types of sample were analyzed by SEM and EDS
  - Peeling coating from quartz substrate by carbon tape
  - Coating flakes picked up by carbon tape
- Quartz substrate
  • Due to non-electrical conduction of yttria coating and quartz, charging may affect quality of SEM images.

5 Summary of Observations
  • Yttria exhibits columnar structure through thickness of coating.
  • Fluorine (-15 at.%) was detected from both front and back sides of yttria coating, and residues with higher F concentration (>30 at. %) observed on the backside of coating.
  • Negligible Si detected on backside of yttria coating.
  • Analysis on cross-section of yttria coating revealed high H concentration in columnar structure.
  • Overall quartz substrate consists of stoichiometric silicon dioxide with polycrystalline structure.
  • Fluoride formed along SiO₂ grain boundaries ("intergranular corrosion"), but the bulk of grains remained intact.
  • Al also detected in grain boundaries, which is possibly segregated impurity (oxide or silicate) and reacts with fluorine to form aluminum fluoride.
  • Possible mechanism of coating delamination: fluorine penetrates yttria coating through columnar structure boundaries and attacks quartz substrate forming fluoride along grain boundaries, cracking yttria coating on top.
  • See FIGs. 6 to 13.

EXAMPLE 3

Example 3 is a comparative example of a yttria only coating on a quartz substrate and a quartz substrate control that were exposed to a fluorine plasma for 6 hours.

30 Two quartz samples in fluorine plasma for 6 hours
  - #1: New quartz sample without yttria coating
- #2: Yttria coated (both side) quartz sample
  - Frontside (exposed in fluorine) and backside (unexposed in fluorine) were both examined by SEM and EDS.
  - No delamination of yttria coating observed on sample #2.
  - See FIGs. 14 to 19.

EXAMPLE 4

Example 4 is an infrared (IR) transmittance of AION coating.
  - Infrared (IR) property of AION coatings was characterized by measuring transmittance of 3µm AION coated sapphire sample in IR spectral range by Fourier transform infrared (FT-IR) spectrometer.
  - AION ceramic (0.125 inch thick) and sapphire (0.02 inch thick) samples as references were also measured IR transmittance.
  - Sapphire has the 100% transmittance in IR range for wavelength 2.7 to 7.5µm. AION coated sapphire has the same IR transparency range as sapphire, but transmittance reduces about 20%. AION ceramic exhibits a slightly less than 80% IR transmittance in a range from wavelength 2.5 to 6µm.
  - See FIG. 20

EXAMPLE 5

Example 5 is a fluorine etch resistance comparison
  - AION coating, bulk Aluminum Oxide, and Aluminum 6061 Alloy were subject to a fluoride plasma.
  - Etch rate measured using masking and profilometry and data is shown in Table 3.
Table 3

<table>
<thead>
<tr>
<th>Material</th>
<th>Etch Rate (μm/h)</th>
</tr>
</thead>
<tbody>
<tr>
<td>AlION (thin film)</td>
<td>0.25</td>
</tr>
<tr>
<td>Aluminum Oxide (Bulk)</td>
<td>0.33</td>
</tr>
<tr>
<td>Aluminum 6061 Alloy</td>
<td>0.66</td>
</tr>
</tbody>
</table>

- AlION coating and Quartz were subject to another fluoride plasma.
- Etch rate measured using masking and profilometry and data is shown in Table 4.

Table 4

<table>
<thead>
<tr>
<th>Material</th>
<th>Erosion Rate (μm/h)</th>
</tr>
</thead>
<tbody>
<tr>
<td>AlION (thin film)</td>
<td>0.6</td>
</tr>
<tr>
<td>Quartz</td>
<td>10.5</td>
</tr>
</tbody>
</table>

These, and other, aspects of the invention will be better appreciated and understood when considered in conjunction with the following description and the accompanying drawings. The following description, while indicating various embodiments of the invention and numerous specific details thereof, is given by way of illustration and not of limitation. Many substitutions, modifications, additions or rearrangements may be made within the scope of the invention, and the invention includes all such substitutions, modifications, additions or rearrangements.
What is claimed is:

1. A substrate comprising a layer of AION overlying the substrate and a optional layer of yttria overlying the AION.

2. The substrate of Claim 1 wherein the AION layer is from about 1 micron to about 10 microns thick.

3. The substrate of Claim 2, wherein the AION layer is from about 2 microns to about 3 microns thick.

4. The substrate of Claim 1, wherein the yttria layer is from about 1 micron to about 10 microns thick.

5. The substrate of Claim 4, wherein the yttria layer is from about 2 microns to about 3 microns thick.

6. The substrate of Claim 1, wherein the AION layer, the yttria layer or both are deposited on the quartz substrate by pulsed reactive physical vapor deposition.

7. The substrate of any one of Claims 1 to 6, wherein the substrate is quartz, alumina, aluminum, steels, metals, alloys or ceramics.

8. The substrate according to Claim 7, wherein the quartz is stoichiometric silicon dioxide with polycrystalline structure.
XPS composition survey of AlON coating and ceramic

FIG. 1B
Coating Surface Morphology

Coating Cross Section

FIG. 1D
Coating delaminates between barrier layer and quartz substrate.
Relatively low concentration of fluorine on backside of coating may indicate that corrosion started from frontside of coating.

FIG. 2
- Exposed quartz substrate exhibits cauliflower-type of micron-size structures.
- Fluorine-rich species detected along the boundaries.

**FIG. 3**
- Cross-section of coating has been analyzed from a fracture.
- Thickness of barrier layer measured about 2 um.
- Thickness of yttria coating measured about 3 um.
- Both coatings are intact after being used in fluorine environment.

**FIG. 4**
- Yttria coating shows smooth and dense surface that is different from frontside of coating flakes.
- No sign of fluorine corrosion.
- Good adhesion strength: no delamination by Scotch tape test.

**FIG. 5**
FIG. 6
FIG. 8
FIG. 9
FIG. 17
FIG. 18
FIG. 19
FIG. 20